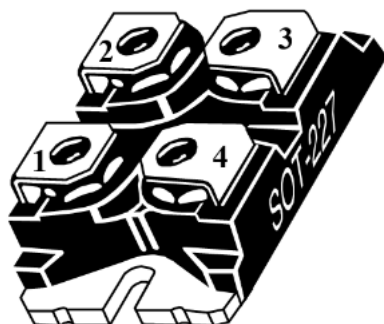
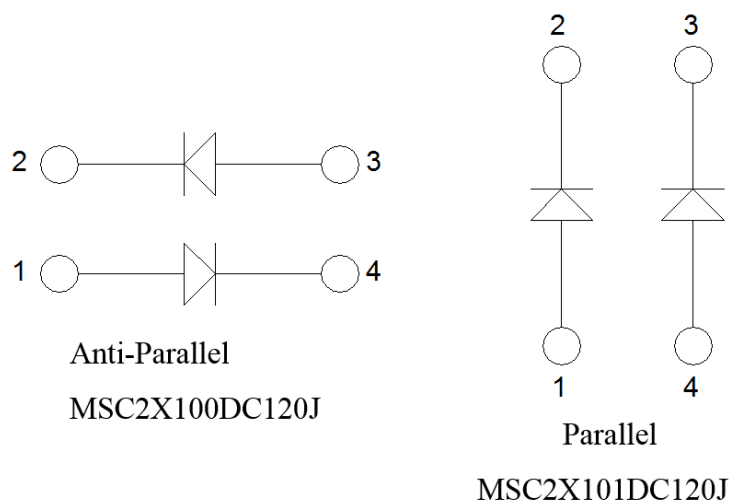


MSC2X101_100DC120J SiC Diode Power Module

1 Product Overview

This section provides the product overview for the MSC2X101_100DC120J device.



All ratings at $T_j = 25^\circ\text{C}$, unless otherwise specified.

Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures should be followed.

1.1 Features

The following are key features of the MSC2X101_100DC120J device:

- Silicon carbide (SiC) Schottky diode
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature-independent switching behavior
 - Positive temperature coefficient on VF
- Very low stray inductance

1.2 Benefits

The following are benefits of the MSC2X101_100DC120J device:

- Outstanding performance at high-frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- RoHS compliant

1.3 Applications

The MSC2X101_100DC120J device is designed for the following applications:

- Uninterruptible power supply (UPS)
- Induction heating
- Welding equipment
- High-speed rectifiers

2 Electrical Specifications

This section provides the electrical specifications for the MSC2X101_100DC120J device.

2.1 Absolute Maximum Ratings

The following table shows the absolute maximum ratings per diode for the MSC2X101_100DC120J device.

Table 1 • Absolute Maximum Ratings

Symbol	Parameter	Maximum Ratings	Unit
V_{RRM}	Repetitive peak reverse voltage	1200	V
I_F	DC forward current	$T_C = 100\text{ }^{\circ}\text{C}$ 100	A

The following table shows the thermal and package characteristics of the MSC2X101_100DC120J.

Table 2 • Thermal and Package Characteristics

Symbol	Characteristic	Min	Typ	Max	Unit
V_{ISOL}	RMS isolation voltage, any terminal to case $t = 1$ minute, 50 Hz/60 Hz	2500			V
T_{JSTG}	Storage temperature range	-55		175	$^{\circ}\text{C}$
T_{JOP}	Recommended junction temperature under switching conditions	-55		$T_{Jmax} - 25$	
Torque	Terminal and mounting screws			1.1	N.m
Wt	Package weight		29.2		g

2.2 Electrical Performance

The following table shows the electrical characteristics per diode of the MSC2X101_100DC120J.

Table 3 • Electrical Characteristics Per Diode

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
V_F	Diode forward voltage	$I_F = 100\text{ A}$ $T_J = 25\text{ }^{\circ}\text{C}$		1.5	1.8	V
		$T_J = 175\text{ }^{\circ}\text{C}$		2.1		
I_{RM}	Reverse leakage current	$V_R = 1200\text{ V}$ $T_J = 25\text{ }^{\circ}\text{C}$		30	400	μA
		$T_J = 175\text{ }^{\circ}\text{C}$		500		
Q_C	Total capacitive charge	$V_R = 600\text{ V}$		448		nC
C	Total capacitance	$f = 1\text{ MHz}$, $V_R = 400\text{ V}$		492		pF
		$f = 1\text{ MHz}$, $V_R = 800\text{ V}$		364		
R_{thJC}	Junction-to-case thermal resistance				0.304	$^{\circ}\text{C/W}$

2.3 Performance Curves

This section shows the typical performance curves for the MSC2X101_100DC120J device.

Figure 1 • Maximum Transient Thermal Impedance

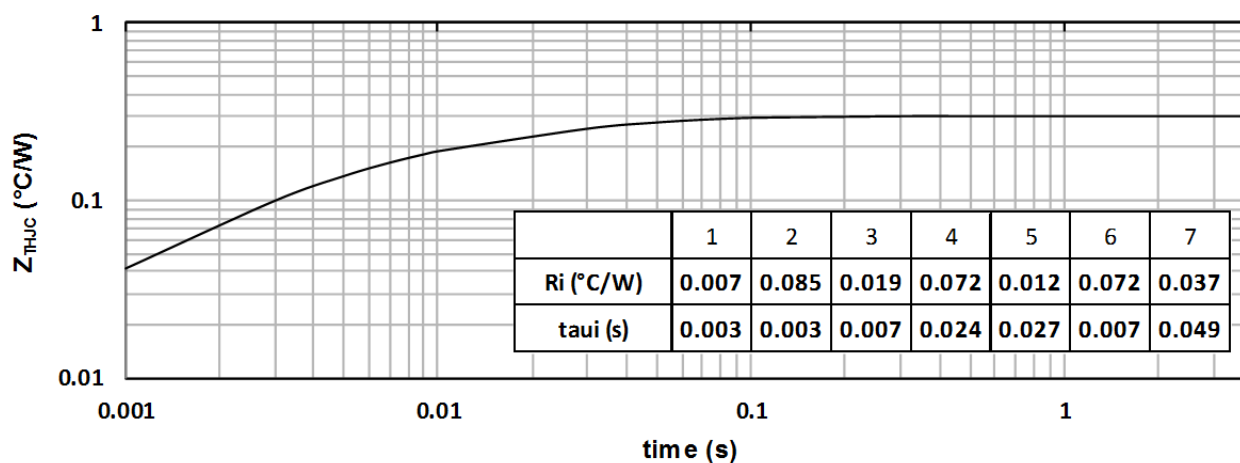


Figure 2 • Forward Current vs. Forward Voltage

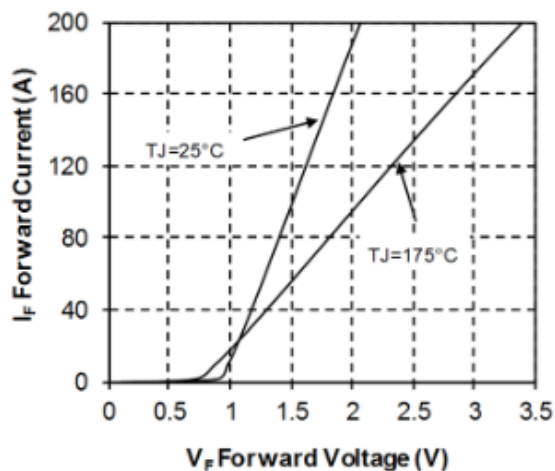
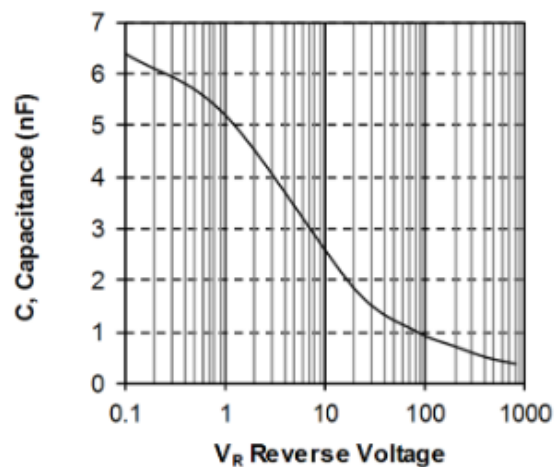


Figure 3 • Capacitance vs. Reverse Voltage



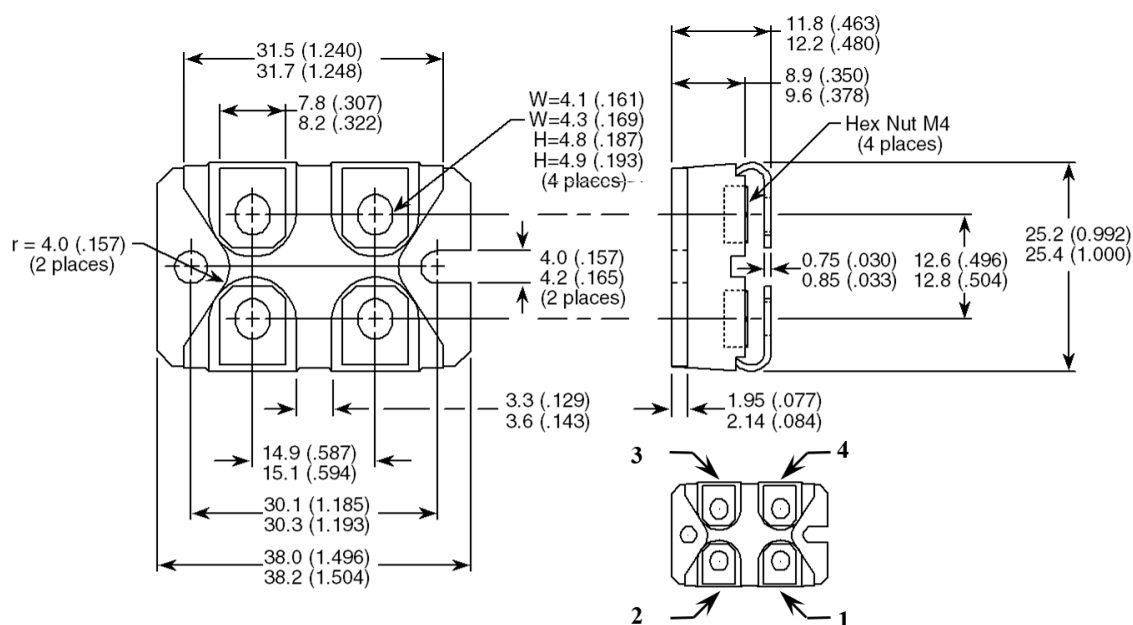
3 Package Specifications

This section shows the package specifications for the MSC2X101_100DC120J device.

3.1 Package Outline Drawing

The following drawing shows the package outline of the MSC2X101_100DC120J device. The dimensions in the following figure are in millimeters.

Figure 4 • Package Outline Drawing



Dimensions in Millimeters and (Inches)

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